ELSEVIER

Surface Science 394 (1997) 251–252

surface science

Author index

Aebi, P., see Fasel 394 (1997) 129
Ascione, F., G. Manicò, A. Bonanno, A. Oliva and F. Xu, On the origin of Ne^{2+} production in low-energy Ne^{+} scattering from Al and Si surfaces 394 (1997) L145

Bardi, U., M. Torrini, Y. Ichinoe, S. Omori, H. Ishii, M. Owari and Y. Nihei, Kikuchi-like effects in X-ray photoelectron diffraction from the $CaF_2(111)$ surface 394 (1997) L150
Bilić, A., see Shen 394 (1997) L131
Björkqvist, M., M. Göthelid and U.O. Karlsson, Nitride formation and dangling-bond passivation on Si(111)-(7 × 7) with NH_3 394 (1997) L155
Blakely, J., see Swanson 394 (1997) 221
Bömermann, J., see Kuntze 394 (1997) 150
Bonanno, A., see Ascione 394 (1997) L145
Bowler, D.R., see Owen 394 (1997) 79
Bowler, D.R., see Owen 394 (1997) 91
Bowler, D.R., see Goldfarb 394 (1997) 105
Briggs, G.A.D., see Owen 394 (1997) 79
Briggs, G.A.D., see Owen 394 (1997) 91
Briggs, G.A.D., see Goldfarb 394 (1997) 105

Celio, H., K. Mudalige, P. Mills and M. Trenary, Formation of isocyanate on Cu(100) from the oxidation of cyanogen and from the decomposition of isocyanic acid 394 (1997) L168
Chen, Q., see Frederick 394 (1997) 1
Chen, Q., see Frederick 394 (1997) 26
Comsa, G., see Tölkes 394 (1997) 170

David, R., see Tölkes 394 (1997) 170
Dhesi, S.S., see Frederick 394 (1997) 26
Dreyssé, H., see Pick 394 (1997) 192

Eckl, C., J. Fritsch, P. Pavone and U. Schröder, Ab initio calculation of phonons in GaP(110) and InAs(110) and trends within III–V(110) surfaces 394 (1997) 47
Ehrlich, G., see Kyuno 394 (1997) L179
Ekerdt, J.G., see Jo 394 (1997) L162
Ertl, G., see Wintterlin 394 (1997) 159
Evangelakis, G.A., G.C. Kallinteris and N.I. Papanicolaou, Molecular dynamics study of gold adatom diffusion on low-index copper surfaces 394 (1997) 185

Fasel, R., P. Aebi, J. Osterwalder and L. Schlapbach, Structural and spectroscopic investigation of the Yb/Al(001) interface in the submonolayer coverage range 394 (1997) 129
Fölsch, S., G. Meyer, K.H. Rieder, M. Horn-von Hoegen, T. Schmidt and M. Henzler, Ag-mediated step-bunching instability on vicinal Si(100) 394 (1997) 60
Frederick, B.G., Q. Chen, F.M. Leibsle, M.B. Lee, K.J. Kitching and N.V. Richardson, Long-range periodicity in c(8 × 2) benzoate/Cu(110): a combined STM, LEED and HREELS study 394 (1997) 1
Frederick, B.G., Q. Chen, F.M. Leibsle, S.S. Dhesi and N.V. Richardson, Electron-stimulated disordering in c(8 × 2) benzoate/Cu(110): a combined STM, LEED and HREELS study 394 (1997) 26
Fritsch, J., see Eckl 394 (1997) 47
Fujieda, K., see Sugawara 394 (1997) L174
Fujiwara, H., see Hoshino 394 (1997) 119

Goldfarb, I., see Owen 394 (1997) 79
Goldfarb, I., see Owen 394 (1997) 91
Goldfarb, I., J.H.G. Owen, P.T. Hayden, D.R. Bowler, K. Miki and G.A.D. Briggs, Gas-source growth of group IV semiconductors: III. Nucleation and growth of Ge/Si(001) 394 (1997) 105
Gołek, F., see Markowski 394 (1997) 144
Gong, B., see Jo 394 (1997) L162
Goringe, C.M., see Owen 394 (1997) 79
Goringe, C.M., see Owen 394 (1997) 91
Göthelid, M., see Björkqvist 394 (1997) L155
Gsell, M., see Kostov 394 (1997) L138

Hayden, P.T., see Goldfarb 394 (1997) 105
Heiland, W., see Kuntze 394 (1997) 150
Henzler, M., see Fölsch 394 (1997) 60
Hess, G., see Jo 394 (1997) L162
Hiraoka, Y.S., Ab initio molecular orbital study on the As-stabilized GaAs(001)-(2 × 4)β_1 surface 394 (1997) 71
Horn-von Hoegen, M., see Fölsch 394 (1997) 60
Hoshino, T., N. Kamijou, H. Fujiwara, T. Watanabe and I. Ohdomari, Theoretical investigation on the formation process of the stacking-fault triangle in the Si(111)-7 × 7 structure 394 (1997) 119

Ichinoe, Y., see Bardi 394 (1997) L150
Ishii, H., see Bardi 394 (1997) L150

Jakob, P., see Kostov 394 (1997) L138
Jo, S.K., B. Gong, G. Hess, J.M. White and J.G. Ekerdt, Low-temperature Si(100) etching: facile abstraction of SiH_3(a) by thermal hydrogen atoms 394 (1997) L162

Kallinteris, G.C., see Evangelakis 394 (1997) 185
Kamijou, N., see Hoshino 394 (1997) 119
Karlsson, U.O., see Björkqvist 394 (1997) L155
King, B.V., see Shen 394 (1997) L131
Kitching, K.J., see Frederick 394 (1997) 1
Kostov, K.L., M. Gsell, P. Jakob, T. Moritz, W. Widdra and D. Menzel, Observation of a novel high density 3O(2×2) structure on Ru(001) 394 (1997) L138
Krzyzowski, M.A., see Tölkes 394 (1997) 170
Kuntze, J., J. Bömermann, T. Rauch, S. Speller and W. Heiland, Surface reconstruction of the Ir(110) surface 394 (1997) 150
Kyuno, K. and G. Ehrlich, Step-edge barriers: truths and kinetic consequences 394 (1997) L179

Lee, M.B., see Frederick 394 (1997) 1
Leibsle, F.M., see Frederick 394 (1997) 1
Leibsle, F.M., see Frederick 394 (1997) 26

Manicò, G., see Ascione 394 (1997) L145
Markowski, L. and F. Gołek, ESD from LiF thin films 394 (1997) 144
Menzel, D., see Kostov 394 (1997) L138
Meyer, G., see Fölsch 394 (1997) 60
Miki, K., see Owen 394 (1997) 79
Miki, K., see Owen 394 (1997) 91
Miki, K., see Goldfarb 394 (1997) 105
Mills, P., see Celio 394 (1997) L168
Moritz, T., see Kostov 394 (1997) L138
Mudalige, K., see Celio 394 (1997) L168

Nihei, Y., see Bardi 394 (1997) L150

O'Connor, D.J., see Shen 394 (1997) L131
Ohdomari, I., see Hoshino 394 (1997) 119
Oliva, A., see Ascione 394 (1997) L145
Omori, S., see Bardi 394 (1997) L150
Osterwalder, J., see Fasel 394 (1997) 129
Otsuka, N., see Sugawara 394 (1997) L174
Owari, M., see Bardi 394 (1997) L150
Owen, J.H.G., K. Miki, D.R. Bowler, C.M. Goringe, I. Goldfarb and G.A.D. Briggs, Gas-source growth of group IV semiconductors: I. Si(001) nucleation mechanisms 394 (1997) 79
Owen, J.H.G., K. Miki, D.R. Bowler, C.M. Goringe, I. Goldfarb and G.A.D. Briggs, Gas-source growth of group IV semiconductors: II. Growth regimes and the effect of hydrogen 394 (1997) 91
Owen, J.H.G., see Goldfarb 394 (1997) 105

Papanicolaou, N.I., see Evangelakis 394 (1997) 185
Pavone, P., see Eckl 394 (1997) 47
Pick, Š. and H. Dreyssé, Model of gas adsorption on magnetic surfaces 394 (1997) 192
Pietzak, B., see Richter 394 (1997) 201

Radny, M.W., see Wang 394 (1997) 235
Rauch, T., see Kuntze 394 (1997) 150
Renisch, S., see Wintterlin 394 (1997) 159
Richardson, N.V., see Frederick 394 (1997) 1
Richardson, N.V., see Frederick 394 (1997) 26
Richter, A., R. Ries, K. Szulzewsky, B. Pietzak and R. Smith, The growth mechanisms and morphology of C_{60} films on different substrates 394 (1997) 201
Rieder, K.H., see Fölsch 394 (1997) 60
Ries, R., see Richter 394 (1997) 201

Schlapbach, L., see Fasel 394 (1997) 129
Schmidt, T., see Fölsch 394 (1997) 60
Schröder, U., see Eckl 394 (1997) 47
Schuster, R., see Wintterlin 394 (1997) 159
Shen, Y.G., A. Bilić, D.J. O'Connor and B.V. King, Reinvestigation of the surface reconstruction of Cu(001)-(2×2)p4g-Pd 394 (1997) L131
Smith, P.V., see Wang 394 (1997) 235
Smith, R., see Richter 394 (1997) 201
Speller, S., see Kuntze 394 (1997) 150
Sugawara, A., K. Fujieda and N. Otsuka, Long period reconstruction of GaAs(001) surface 394 (1997) L174
Swanson, A. and J. Blakely, Structure and modification of silver halide thin films using scanning tunneling and atomic force microscopy 394 (1997) 221
Szulzewsky, K., see Richter 394 (1997) 201

Tölkes, C., P. Zeppenfeld, M.A. Krzyzowski, R. David and G. Comsa, Growth and stability of cobalt nanostructures on gold (111) 394 (1997) 170
Torrini, M., see Bardi 394 (1997) L150
Trenary, M., see Celio 394 (1997) L168
Trost, J., see Wintterlin 394 (1997) 159

Wang, S., M.W. Radny and P.V. Smith, Ab initio cluster calculations of the chemisorption of hydrogen on the Si(111) Si(111)$\sqrt{3} \times \sqrt{3}$R30°-B surface 394 (1997) 235
Watanabe, T., see Hoshino 394 (1997) 119
White, J.M., see Jo 394 (1997) L162
Widdra, W., see Kostov 394 (1997) L138
Wintterlin, J., J. Trost, S. Renisch, R. Schuster, T. Zambelli and G. Ertl, Real-time STM observations of atomic equilibrium fluctuations in an adsorbate system: O/Ru(0001) 394 (1997) 159

Xu, F., see Ascione 394 (1997) L145

Zambelli, T., see Wintterlin 394 (1997) 159
Zeppenfeld, P., see Tölkes 394 (1997) 170

ELSEVIER

Surface Science 394 (1997) 253–256

surface science

Subject index

THEORETICAL METHODS, MODELS AND TECHNIQUES

Ab initio quantum chemical methods and calculations

B.G. Frederick, Q. Chen, F.M. Leibsle, M.B. Lee, K.J. Kitching and N.V. Richardson, Long-range periodicity in c(8 × 2) benzoate/Cu(110): a combined STM, LEED and HREELS study 394 (1997) 1

Y.S. Hiraoka, Ab initio molecular orbital study on the As-stabilized GaAs(001)-(2 × 4)β_1 surface 394 (1997) 71

S. Wang, M.W. Radny and P.V. Smith, Ab initio cluster calculations of the chemisorption of hydrogen on the Si(111)$\sqrt{3} \times \sqrt{3}$R30°-B surface 394 (1997) 235

Density functional calculations

J.H.G. Owen, K. Miki, D.R. Bowler, C.M. Goringe, I. Goldfarb and G.A.D. Briggs, Gas-source growth of group IV semiconductors: I. Si(001) nucleation mechanisms 394 (1997) 79

J.H.G. Owen, K. Miki, D.R. Bowler, C.M. Goringe, I. Goldfarb and G.A.D. Briggs, Gas-source growth of group IV semiconductors: II. Growth regimes and the effect of hydrogen 394 (1997) 91

Electron–solid interactions, scattering, diffraction

S. Fölsch, G. Meyer, K.H. Rieder, M. Horn-von Hoegen, T. Schmidt and M. Henzler, Ag-mediated step-bunching instability on vicinal Si(100) 394 (1997) 60

Models of surface chemical reactions

J.H.G. Owen, K. Miki, D.R. Bowler, C.M. Goringe, I. Goldfarb and G.A.D. Briggs, Gas-source growth of group IV semiconductors: I. Si(001) nucleation mechanisms 394 (1997) 79

Models of surface kinetics

K. Kyuno and G. Ehrlich, Step-edge barriers: truths and kinetic consequences 394 (1997) L179

B.G. Frederick, Q. Chen, F.M. Leibsle, S.S. Dhesi and N.V. Richardson, Electron-stimulated disordering in c(8 × 2) benzoate/Cu(110): a combined STM, LEED and HREELS study 394 (1997) 26

Molecular dynamics

G.A. Evangelakis, G.C. Kallinteris and N.I. Papanicolaou, Molecular dynamics study of gold adatom diffusion on low-index copper surfaces 394 (1997) 185

Semi-empirical models and model calculations

T. Hoshino, N. Kamijou, H. Fujiwara, T. Watanabe and I. Ohdomari, Theoretical investigation on the formation process of the stacking-fault triangle in the Si(111)-7 × 7 structure 394 (1997) 119

Š. Pick and H. Dreyssé, Model of gas adsorption on magnetic surfaces 394 (1997) 192

EXPERIMENTAL SAMPLE PREPARATION AND CHARACTERIZATION METHODS

Atom–solid scattering and diffraction – elastic

C. Tölkes, P. Zeppenfeld, M.A. Krzyzowski, R. David and G. Comsa, Growth and stability of cobalt nanostructures on gold (111) 394 (1997) 170

Atom–solid scattering and diffraction – inelastic

F. Ascione, G. Manicò, A. Bonanno, A. Oliva and F. Xu, On the origin of Ne^{2+} production in low-energy Ne^{+} scattering from Al and Si surfaces 394 (1997) L145

Atomic force microscopy

A. Swanson and J. Blakely, Structure and modification of silver halide thin films using scanning tunneling and atomic force microscopy 394 (1997) 221

Auger electron spectroscopy

C. Tölkes, P. Zeppenfeld, M.A. Krzyzowski, R. David and G. Comsa, Growth and stability of cobalt nanostructures on gold (111) 394 (1997) 170

Chemical vapor deposition

J.H.G. Owen, K. Miki, D.R. Bowler, C.M. Goringe, I. Goldfarb and G.A.D. Briggs, Gas-source growth of group IV semiconductors: I. Si(001) nucleation mechanisms 394 (1997) 79

J.H.G. Owen, K. Miki, D.R. Bowler, C.M. Goringe, I. Goldfarb and G.A.D. Briggs, Gas-source growth of group IV semiconductors: II. Growth regimes and the effect of hydrogen 394 (1997) 91

Desorption induced by electronic transitions (DIET)

B.G. Frederick, Q. Chen, F.M. Leibsle, S.S. Dhesi and N.V. Richardson, Electron-stimulated disordering in c(8 × 2) benzoate/Cu(110): a combined STM, LEED and HREELS study 394 (1997) 26

Electron stimulated desorption (ESD)

B.G. Frederick, Q. Chen, F.M. Leibsle, S.S. Dhesi and N.V. Richardson, Electron-stimulated disordering in c(8 × 2) benzoate/Cu(110): a combined STM, LEED and HREELS study 394 (1997) 26

L. Markowski and F. Gołek, ESD from LiF thin films 394 (1997) 144

Electron energy loss spectroscopy

K.L. Kostov, M. Gsell, P. Jakob, T. Moritz, W. Widdra and D. Menzel, Observation of a novel high density 3O(2 × 2) structure on Ru(001) 394 (1997) L138

B.G. Frederick, Q. Chen, F.M. Leibsle, M.B. Lee, K.J. Kitching and N.V. Richardson, Long-range periodicity in c(8 × 2) benzoate/Cu(110): a combined STM, LEED and HREELS study 394 (1997) 1

B.G. Frederick, Q. Chen, F.M. Leibsle, S.S. Dhesi and N.V. Richardson, Electron-stimulated disordering in c(8 × 2) benzoate/Cu(110): a combined STM, LEED and HREELS study 394 (1997) 26

Electron–solid diffraction

Low energy electron diffraction (LEED)

S. Fölsch, G. Meyer, K.H. Rieder, M. Horn-von Hoegen, T. Schmidt and M. Henzler, Ag-mediated step-bunching instability on vicinal Si(100) 394 (1997) 60

R. Fasel, P. Aebi, J. Osterwalder and L. Schlapbach, Structural and spectroscopic investigation of the Yb/Al(001) interface in the submonolayer coverage range 394 (1997) 129

Photoelectron diffraction

U. Bardi, M. Torrini, Y. Ichinoe, S. Omori, H. Ishii, M. Owari and Y. Nihei, Kikuchi-like effects in X-ray photoelectron diffraction from the CaF_2(111) surface 394 (1997) L150

R. Fasel, P. Aebi, J. Osterwalder and L. Schlapbach, Structural and spectroscopic investigation of the Yb/Al(001) interface in the submonolayer coverage range 394 (1997) 129

Reflection high-energy electron diffraction (HREED)

A. Sugawara, K. Fujieda and N. Otsuka, Long period reconstruction of GaAs(001) surface 394 (1997) L174

Ion scattering spectroscopy

Low energy ion scattering (LEIS)

Y.G. Shen, A. Bilić, D.J. O'Connor and B.V. King, Reinvestigation of the surface reconstruction of Cu(001)-(2 × 2)p4g-Pd 394 (1997) L131

F. Ascione, G. Manicò, A. Bonanno, A. Oliva and F. Xu, On the origin of Ne^{2+} production in low-energy Ne^{+} scattering from Al and Si surfaces 394 (1997) L145

Molecular beam epitaxy

C. Tölkes, P. Zeppenfeld, M.A. Krzyzowski, R. David and G. Comsa, Growth and stability of cobalt nanostructures on gold (111) 394 (1997) 170

Photoelectron spectroscopy

Visible and ultraviolet photoelectron spectroscopy

R. Fasel, P. Aebi, J. Osterwalder and L. Schlapbach, Structural and spectroscopic investigation of the Yb/Al(001) interface in the submonolayer coverage range 394 (1997) 129

Photon absorption spectroscopy

Infrared absorption spectroscopy

H. Celio, K. Mudalige, P. Mills and M. Trenary, Formation of isocyanate on Cu(100) from the oxidation of cyanogen and from the decomposition of isocyanic acid 394 (1997) L168

Scanning tunneling microscopy

K.L. Kostov, M. Gsell, P. Jakob, T. Moritz, W. Widdra and D. Menzel, Observation of a novel high density 3O(2 × 2) structure on Ru(001) 394 (1997) L138

M. Björkqvist, M. Göthelid and U.O. Karlsson, Nitride formation and dangling-bond passivation on Si(111)-(7 × 7) with NH_3 394 (1997) L155

B.G. Frederick, Q. Chen, F.M. Leibsle, M.B. Lee, K.J. Kitching and N.V. Richardson, Long-range periodicity in c(8 × 2) benzoate/Cu(110): a combined STM, LEED and HREELS study 394 (1997) 1

B.G. Frederick, Q. Chen, F.M. Leibsle, S.S. Dhesi and N.V. Richardson, Electron-stimulated disordering in c(8 × 2) benzoate/Cu(110): a combined STM, LEED and HREELS study 394 (1997) 26

S. Fölsch, G. Meyer, K.H. Rieder, M. Horn-von Hoegen, T. Schmidt and M. Henzler, Ag-mediated step-bunching instability on vicinal Si(100) 394 (1997) 60

J.H.G. Owen, K. Miki, D.R. Bowler, C.M. Goringe, I. Goldfarb and G.A.D. Briggs, Gas-source growth of group IV semiconductors: I. Si(001) nucleation mechanisms 394 (1997) 79

J.H.G. Owen, K. Miki, D.R. Bowler, C.M. Goringe, I. Goldfarb and G.A.D. Briggs, Gas-source growth of group IV semiconductors: II. Growth regimes and the effect of hydrogen 394 (1997) 91

I. Goldfarb, J.H.G. Owen, P.T. Hayden, D.R. Bowler, K. Miki and G.A.D. Briggs, Gas-source growth of group IV semi-

conductors: III. Nucleation and growth of Ge/Si(001) 394 (1997) 105
J. Kuntze, J. Bömermann, T. Rauch, S. Speller and W. Heiland, Surface reconstruction of the Ir(110) surface 394 (1997) 150
J. Wintterlin, J. Trost, S. Renisch, R. Schuster, T. Zambelli and G. Ertl, Real-time STM observations of atomic equilibrium fluctuations in an adsorbate system: O/Ru(0001) 394 (1997) 159
A. Swanson and J. Blakely, Structure and modification of silver halide thin films using scanning tunneling and atomic force microscopy 394 (1997) 221

Scanning tunneling spectroscopies

B.G. Frederick, Q. Chen, F.M. Leibsle, S.S. Dhesi and N.V. Richardson, Electron-stimulated disordering in c(8 × 2) benzoate/Cu(110): a combined STM, LEED and HREELS study 394 (1997) 26

X-ray scattering, diffraction, and reflection

A. Richter, R. Ries, K. Szulzewsky, B. Pietzak and R. Smith, The growth mechanisms and morphology of C_{60} films on different substrates 394 (1997) 201

PHENOMENA

Atom–solid interactions

F. Ascione, G. Manicò, A. Bonanno, A. Oliva and F. Xu, On the origin of Ne^{2+} production in low-energy Ne^{+} scattering from Al and Si surfaces 394 (1997) L145

Chemisorption

K.L. Kostov, M. Gsell, P. Jakob, T. Moritz, W. Widdra and D. Menzel, Observation of a novel high density 3O(2 × 2) structure on Ru(001) 394 (1997) L138
S.K. Jo, B. Gong, G. Hess, J.M. White and J.G. Ekerdt, Low-temperature Si(100) etching: facile abstraction of SiH_3(a) by thermal hydrogen atoms 394 (1997) L162
H. Celio, K. Mudalige, P. Mills and M. Trenary, Formation of isocyanate on Cu(100) from the oxidation of cyanogen and from the decomposition of isocyanic acid 394 (1997) L168
B.G. Frederick, Q. Chen, F.M. Leibsle, M.B. Lee, K.J. Kitching and N.V. Richardson, Long-range periodicity in c(8 × 2) benzoate/Cu(110): a combined STM, LEED and HREELS study 394 (1997) 1
J. Wintterlin, J. Trost, S. Renisch, R. Schuster, T. Zambelli and G. Ertl, Real-time STM observations of atomic equilibrium fluctuations in an adsorbate system: O/Ru(0001) 394 (1997) 159
Š. Pick and H. Dreyssé, Model of gas adsorption on magnetic surfaces 394 (1997) 192
S. Wang, M.W. Radny and P.V. Smith, Ab initio cluster calculations of the chemisorption of hydrogen on the Si(111)$\sqrt{3} \times \sqrt{3}$R30°-B surface 394 (1997) 235

Diffusion and migration

B.G. Frederick, Q. Chen, F.M. Leibsle, S.S. Dhesi and N.V. Richardson, Electron-stimulated disordering in c(8 × 2) benzoate/Cu(110): a combined STM, LEED and HREELS study 394 (1997) 26

Electron stimulated desorption

B.G. Frederick, Q. Chen, F.M. Leibsle, S.S. Dhesi and N.V. Richardson, Electron-stimulated disordering in c(8 × 2) benzoate/Cu(110): a combined STM, LEED and HREELS study 394 (1997) 26

Epitaxy

K. Kyuno and G. Ehrlich, Step-edge barriers: truths and kinetic consequences 394 (1997) L179
Y.S. Hiraoka, Ab initio molecular orbital study on the As-stabilized GaAs(001)-(2 × 4)β_1 surface 394 (1997) 71
I. Goldfarb, J.H.G. Owen, P.T. Hayden, D.R. Bowler, K. Miki and G.A.D. Briggs, Gas-source growth of group IV semiconductors: III. Nucleation and growth of Ge/Si(001) 394 (1997) 105
A. Swanson and J. Blakely, Structure and modification of silver halide thin films using scanning tunneling and atomic force microscopy 394 (1997) 221

Growth

Y.G. Shen, A. Bilić, D.J. O'Connor and B.V. King, Reinvestigation of the surface reconstruction of Cu(001)-(2 × 2)p4g-Pd 394 (1997) L131
M. Björkqvist, M. Göthelid and U.O. Karlsson, Nitride formation and dangling-bond passivation on Si(111)-(7 × 7) with NH_3 394 (1997) L155
K. Kyuno and G. Ehrlich, Step-edge barriers: truths and kinetic consequences 394 (1997) L179
I. Goldfarb, J.H.G. Owen, P.T. Hayden, D.R. Bowler, K. Miki and G.A.D. Briggs, Gas-source growth of group IV semiconductors: III. Nucleation and growth of Ge/Si(001) 394 (1997) 105

Magnetic phenomena (cyclotron resonance, phase transitions, etc.)

Š. Pick and H. Dreyssé, Model of gas adsorption on magnetic surfaces 394 (1997) 192

Nucleation

K. Kyuno and G. Ehrlich, Step-edge barriers: truths and kinetic consequences 394 (1997) L179

Oxidation

H. Celio, K. Mudalige, P. Mills and M. Trenary, Formation of isocyanate on Cu(100) from the oxidation of cyanogen and from the decomposition of isocyanic acid 394 (1997) L168

Self-assembly

B.G. Frederick, Q. Chen, F.M. Leibsle, M.B. Lee, K.J. Kitching and N.V. Richardson, Long-range periodicity in c(8 × 2) benzoate/Cu(110): a combined STM, LEED and HREELS study 394 (1997) 1

Surface chemical reaction

M. Björkqvist, M. Göthelid and U.O. Karlsson, Nitride formation and dangling-bond passivation on Si(111)-(7 × 7) with NH_3 394 (1997) L155

S. Wang, M.W. Radny and P.V. Smith, Ab initio cluster calculations of the chemisorption of hydrogen on the Si(111)$\sqrt{3} \times \sqrt{3}$R30°-B surface 394 (1997) 235

Surface diffusion

K. Kyuno and G. Ehrlich, Step-edge barriers: truths and kinetic consequences 394 (1997) L179

J. Wintterlin, J. Trost, S. Renisch, R. Schuster, T. Zambelli and G. Ertl, Real-time STM observations of atomic equilibrium fluctuations in an adsorbate system: O/Ru(0001) 394 (1997) 159

G.A. Evangelakis, G.C. Kallinteris and N.I. Papanicolaou, Molecular dynamics study of gold adatom diffusion on low-index copper surfaces 394 (1997) 185

Surface electronic phenomena (work function, surface potential, surface states, etc.)

R. Fasel, P. Aebi, J. Osterwalder and L. Schlapbach, Structural and spectroscopic investigation of the Yb/Al(001) interface in the submonolayer coverage range 394 (1997) 129

Surface relaxation and reconstruction

C. Eckl, J. Fritsch, P. Pavone and U. Schröder, Ab initio calculation of phonons in GaP(110) and InAs(110) and trends within III–V(110) surfaces 394 (1997) 47

Y.S. Hiraoka, Ab initio molecular orbital study on the As-stabilized GaAs(001)-(2 × 4)β_1 surface 394 (1997) 71

T. Hoshino, N. Kamijou, H. Fujiwara, T. Watanabe and I. Ohdomari, Theoretical investigation on the formation process of the stacking-fault triangle in the Si(111)-7 × 7 structure 394 (1997) 119

R. Fasel, P. Aebi, J. Osterwalder and L. Schlapbach, Structural and spectroscopic investigation of the Yb/Al(001) interface in the submonolayer coverage range 394 (1997) 129

Surface roughening

I. Goldfarb, J.H.G. Owen, P.T. Hayden, D.R. Bowler, K. Miki and G.A.D. Briggs, Gas-source growth of group IV semiconductors: III. Nucleation and growth of Ge/Si(001) 394 (1997) 105

Surface structure, morphology, roughness, and topography

Y.G. Shen, A. Bilić, D.J. O'Connor and B.V. King, Reinvestigation of the surface reconstruction of Cu(001)-(2 × 2)p4g-Pd 394 (1997) L131

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